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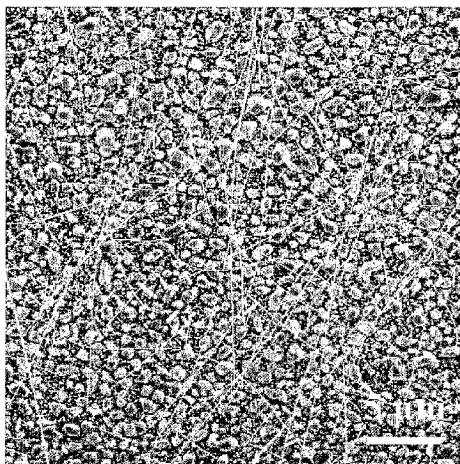
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[Fig. 1]



(57) Abstract: The present invention provides a method for fabricating a single crystalline noble metal nanowire using noble metal oxide, noble metal material or noble metal halide as a precursor and a single crystalline noble metal nanowire, and more particularly a method for fabricating a single crystalline noble metal nanowire on a single crystalline substrate by heat treating a precursor located at a front portion of a furnace and a substrate located at a rear portion of the furnace in an inert flow atmosphere and a single crystalline noble metal nanowire fabricated by the fabrication method. The present invention fabricates a single crystalline noble metal nanowire by non-catalytic vapor phase transport method, the process is simple and reproducible, the fabricated nanowire is a defect free and impurity free, high quality and high purity noble metal nanowire of complete single crystal state.



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A. CLASSIFICATION OF SUBJECT MATTER***B82B 3/00(2006.01)i***

According to International Patent Classification (IPC) or to both national classification and IPC

B. FIELDS SEARCHED

Minimum documentation searched (classification system followed by classification symbols)

IPC B82B, C30B

Documentation searched other than minimum documentation to the extent that such documents are included in the fields searched

Korean Utility models and applications for Utility models since 1975

Japanese Utility models and applications for Utility models since 1975

Electronic data base consulted during the international search (name of data base and, where practicable, search terms used)

eKIPASS (KIPO internal)

C. DOCUMENTS CONSIDERED TO BE RELEVANT

Category*	Citation of document, with indication, where appropriate, of the relevant passages	Relevant to claim No.
X A	HONG, BYUNG HEE et al., Ultrathin Single-Crystalline Silver Nanowire Arrays Formed in an Ambient Solution Phase, Science, 12 October 2001, Vol. 294, No. 348, pp. 348-351. See abstract	17-22 1-16, 23-58
X A	RAMIN BANAN SADEGHIAN and MOJTABA KAHRIZI, 'A Low Pressure Gas Ionization Sensor Using Freestanding Gold Nanowires'. In: 2007 IEEE International Symposium on Industrial Electronics (ISIE 2007). 4-7 June 2007, pp. 1387-1390. See abstract	17, 23-24 1-16, 18-22, 25-58
X A	KIM, KYUNGTAЕ and CHO, SUNG M., 'Pd nanowire sensors for hydrogen detection'. In: Sensors, 2004, Proceedings of IEEE. 24-27 October 2004, Vol. 2, pp. 705-707. See abstract	17, 25-26 1-16, 18-24, 27-58
A	JP 2006-117519 A (SHARP KABUSHIKI KAISHA) 11 May 2006 See abstract, claims 1-51	1-58
A	WO 2003/068674 A1 (JAPAN SCIENCE AND TECHNOLOGY CORPORATION et al.) 21 August 2003 See abstract	1-58

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JP 2006-117519 A	11.05.2006	US 7255745 B2 US 7438759 B2 US 2006-0086314 A1 US 2006-086314 A1	14.08.2007 21.10.2008 27.04.2006 27.04.2006
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